

## **Quarterly Reliability Monitoring Results**

## Quarters: Q1/2022 to Q4/2023

Based on structural similarity

User Part Number						
PMEG3030EXE-Q						
Part Description						
Nexperia DHAM	Schottky					
SMD package						
Test Conditions	Duration	# Lots	# Quantity	# Rejects		
Tamb = 25 °C	N/A	see below	all parts	see below		
JESD22-A113						
Bake Tamb = 125 °C	24 hours					
•						
Reflow soldering	3 cycles	1514	64430	0		
MIL-STD-750-1						
reverse voltage <sup>[1]</sup>	1000 hours	206	9320	0		
JECD22 A104						
	1000 evelen	211	14000	0		
-03 C to IJillax, flot to exceed 130 C	1000 cycles	311	14080	U		
IESD22-A118						
Tamb = 130 °C, RH = 85 %	96 hours 311		14080	0		
JESD22-Δ102		311				
,						
JESD22-A101						
Tamb = 85 °C, RH = 85%, VR = 80 % of						
ias rated reverse voltage <sup>[1], [2]</sup>	1000 hours	311	14080	0		
MIL-STD-750 Method 1037						
ton = toff, devices powered to insure $\Delta T_i$ =						
	1000 hours	312	14120	0		
JESD22-A111						
eat 260 °C ± 5 °C	10 s	269	8070	0		
J-STD-002		222	6660	0		
3	Part Description Nexperia DHAM SMD package  Test Conditions  Tamb = 25 °C  JESD22-A113 Bake Tamb = 125 °C Soak Tamb = 85 °C, RH = 85% Reflow soldering MIL-STD-750-1 M1038 Method A erse Tj = Tjmax, Vr = 100% of max. datasheet reverse voltage <sup>[1]</sup> JESD22-A104 -65 °C to Tjmax, not to exceed 150°C  JESD22-A118 Tamb = 130 °C, RH = 85 % JESD22-A102 Tamb = 121 °C, RH = 100 % Pressure = 205 kPa (29.7 psia)  JESD22-A101 Tamb = 85 °C, RH = 85%, VR = 80 % of rated reverse voltage <sup>[1], [2]</sup> MIL-STD-750 Method 1037 ton = toff, devices powered to insure ΔTj = Life 100 °C for 15000 cycles  JESD22-A111 eat 260 °C ± 5 °C	Part Description   Nexperia DHAM   SMD package	Part Description   Nexperia DHAM   SMD package	Part Description   Nexperia DHAM   Schottky   SMD package		

<sup>[1]</sup> The physical limitations of Schottky diodes have to be considered (thermal runaway).

## **Calculation of FIT and MTTF**

Test considered for FIT calculation: High Temperature Reverse Bias (HTRB, Test #B1) Confidence level 60%, derated to 55 °C, activation energy 0.7 eV, test time 168 to 1000 hours

Wafer Fab	Technology	Quantity	Rejects	Failure Rate (FIT)	MTTF (hrs)
Nexperia					
DHAM	Schottky	9320	0	0,46	2,19E+09

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<sup>[2]</sup> The maximum applied voltage is limited by test chamber set up and does not exceed 115V.